TITLE OF THE INVENTION

MAGNETIC RECORDING MEDIUM AND MAGNETIC

RECORDING/REPRODUCING APPARATUS

CROSS-REFERENCE TO RELATED APPLICATIONS

5   This application is based upon and claims the

benefit of priority from prior Japanese Patent

Application No. 2003-053818, filed February 28, 2003,

the entire contents of which are incorporated herein by

reference.

10   BACKGROUND OF THE INVENTION

1.   Field of the Invention

The present invention relates to a magnetic

recording medium for use in, e.g., a hard disk drive

using the magnetic recording technique, and a magnetic

15   recording/reproducing apparatus using the magnetic

recording medium.

2.   Description of the Related Art

The recording density of a hard disk drive (HDD)

as one type of a magnetic recording/reproducing

20   apparatus is increasing by 60% or more per year, and

this tendency presumably continues in the future.

Therefore, a magnetic recording head and magnetic

recording medium meeting this high recording density

are being developed.

25   A magnetic recording medium contained in a

magnetic recording/reproducing apparatus presently put

on the market has a structure in which a Co alloy film

containing Co as a main component is formed on an Al

alloy substrate or glass substrate by sputtering.

Since the longitudinal magnetization system is used as

a magnetic recording system, an underlayer for

5   orienting the easy axis of magnetization, i.e., the C

axis of Co crystal grains having the hcp structure

parallel to the substrate is used. An example of this

underlayer is a Cr alloy film in which a specific face

of the fcc structure is oriented. In addition, a seed

10   layer, e.g., an NiAl seed layer, for decreasing the

grain size by growing a specific face of Cr is used. A

measure to counter the problem that the holding period

of recorded information shortens by thermal decay as

the recording density increases is demanded. There-

15   fore, a longitudinal magnetic recording medium is

developed in which multiple layers are antiferro-

magnetically coupled with each other by a multilayered

structure formed by sandwiching a thin Ru film between

magnetic films.

20   Also, as a method more suited to high density,

a perpendicular magnetic recording system using

perpendicular magnetization in recording is being

extensively studied. In this system, the same Co alloy

as used in the longitudinal medium is used as a

25   recording layer. However, to perpendicularly orient

the C axes of Co crystal grains, amorphous such as Ge

or NiTa or an underlayer such as Ti, Ru, Pd, or Pt in

which the closest packed plane of hcp or fcc is oriented is used. In addition, to ensure a perpendicular write magnetic field, a soft magnetic layer is formed between the substrate and the underlayer and seed layer and combined with a single pole head, thereby obtaining better perpendicular recording.

To reduce the noise of the perpendicular magnetic recording medium, Jpn. Pat. Appln. KOKAI Publication No. 11-296833, for example, proposes a method by which a double-layered perpendicular magnetic recording layer is used, and the content of a nonmagnetic element in the upper layer is made smaller than that in the lower layer, thereby making the saturation magnetization and magnetic anisotropic energy in the upper layer larger than those in the lower layer.

Furthermore, techniques of controlling thermal decay of the perpendicular magnetic recording medium are also disclosed. Examples currently being studied are a method of forming a Pt film on the surface of a recording layer, and a CGC (Continuous Granular Composite) medium in which a film having a strong magnetic interaction in the film is formed on a CoCrPt-based magnetic film.

To increase the recording/reproduction resolution, it is known to, e.g., shorten the shield gap length of an MR head, reduce the space between the head and the magnetic recording medium, decrease the film thickness

in the longitudinal magnetic recording medium, decrease the distance between the head and the backing soft magnetic film in the perpendicular magnetic recording medium, or reduce the coercive force dispersion.

5   Unfortunately, the conventional magnetic recording media and recording/reproducing apparatuses are unsatisfactory in performance for the purpose of high-density recording, and require further improvements.

10   As described above, reducing the coercive force dispersion or the like of the magnetic recording medium is presumably advantageous to increase the recording resolution. However, no method capable of further reducing the coercive force dispersion of the current

15 magnetic recording media has been found yet.

BRIEF SUMMARY OF THE INVENTION

First, the present invention provides a magnetic recording medium comprising, on a substrate, a multi-layer including a magnetic recording layer and a

20 high-magnetostriction layer having magnetostriction larger than that of the magnetic recording layer.

Second, the present invention provides a magnetic recording apparatus characterized by comprising a recording medium which comprises, on a substrate, a

25 multi-layer including a magnetic recording layer and a high-magnetostriction layer having magnetostriction larger than that of the magnetic recording layer, and a

recording/reproducing head.

BRIEF DESCRIPTION OF THE SEVERAL VIEWS OF THE DRAWING

The accompanying drawings, which are incorporated in and constitute a part of the specification,

5   illustrate embodiments of the invention and, together with the general description given above and the detailed description of the embodiments given below, serve to explain the principles of the invention.

FIG. 1 is a schematic sectional view showing

10   the arrangement of the first example of a magnetic recording medium of the present invention;

FIG. 2 is a schematic sectional view showing the arrangement of the second example of the magnetic recording medium of the present invention;

15   FIG. 3 is a schematic sectional view showing the arrangement of the third example of the magnetic recording medium of the present invention;

FIG. 4 is a schematic sectional view showing the arrangement of the fourth example of the magnetic

20   recording medium of the present invention;

FIG. 5 is a schematic sectional view showing the arrangement of the fifth example of the magnetic recording medium of the present invention;

FIG. 6 is a perspective view showing the

25   arrangement of an example of a magnetic recording/ reproducing apparatus of the present invention;

FIG. 7 is a schematic sectional view showing the

arrangement of the sixth example of the magnetic
recording medium of the present invention;

FIG. 8 is a schematic sectional view showing the
arrangement of the seventh example of the magnetic
recording medium of the present invention;

FIG. 9 is a schematic sectional view showing the
arrangement of the eighth example of the magnetic
recording medium of the present invention;

FIG. 10 is a schematic sectional view showing the
arrangement of the ninth example of the magnetic
recording medium of the present invention;

FIG. 11 is a schematic sectional view showing the
arrangement of the 10th example of the magnetic
recording medium of the present invention;

FIG. 12 is a schematic sectional view showing the
arrangement of the 11th example of the magnetic
recording medium of the present invention; and

FIG. 13 is a schematic sectional view showing the
arrangement of the 12th example of the magnetic
recording medium of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

A magnetic recording medium of the present
invention comprises, on a substrate, a multi-layer
including a magnetic recording layer and a high-
magnetostriction layer having magnetostriction larger
than that of the magnetic recording layer.

The magnetic recording layer is a magnetic layer

having large magnetic anisotropy capable of recording
information.   In the present invention, the high-
magnetostriction layer is a magnetic layer having
magnetostriction larger than that of the magnetic
5   recording layer.

In the present invention, when a magnetic field is
applied during information recording, deformations
appear in the high-magnetostriction layer, and this
produces deformations in the magnetic recording layer.
10   The inverse magnetostriction effect decreases the
anisotropy of the magnetic recording layer to allow
easy magnetization reversal.   The larger the head
magnetic field during recording, the larger the
magnetostriction, and the smaller the anisotropy.
15   Consequently, the magnetization curve of the medium
substantially becomes steep to achieve the same effect
as when the anisotropic dispersion decreases.   This
makes the magnetization transition region short and
steep.   Since the coercive force dispersion
20   substantially decreases and this decreases the
magnetization transition width, the recording
resolution increases.   Also, the magnetization
transition length decreases to make an anisotropic
magnetic field Hk uniform, so the medium S/N ratio
25   increases.

Furthermore, when the head magnetic field is
removed after recording, the magnetostriction

disappears, and this removes the deformations in the recording layer. This prevents the magnetic anisotropy from changing in such a direction as to increase, so the thermal decay resistance does not lower.

A magnetic recording/reproducing apparatus of the present invention has the magnetic recording medium described above and a recording/reproducing head.

When a perpendicular magnetic recording system is applied, a single pole head can be used as the recording/reproducing head.

The present invention will be described in more detail below with reference to the accompanying drawing.

FIG. 1 is a schematic sectional view showing the arrangement of the first example of the magnetic recording medium of the present invention.

As shown in FIG. 1, a magnetic recording medium 10 comprises a substrate 1 made of, e.g., crystallized glass, and a multi-layer 4 including a magnetic recording layer 2 and a high-magnetostriction layer 3 made of, e.g., $Sm_{0.5}Dy_{0.5}Fe_2$, formed in this order on the substrate 1.

The high-magnetostriction layer 3 in the multi-layer 4 can be formed in a position where strain of the high-magnetostriction layer 3 has influence on the magnetic recording layer 2. Referring to FIG. 1, the substrate, magnetic recording layer, and

high-magnetostriction layer are stacked in this order.
However, it is also possible to stack the high-
magnetostriction layer and magnetic recording layer
in this order on the substrate. Furthermore, an
5   interlayer can also be formed between the magnetic
recording layer and high-magnetostriction layer.
Alternatively, a high-magnetostriction layer can be
formed in at least one portion between two or more
magnetic recording layers. This structure is
10   particularly effective when no sufficient strain can be
easily given to the magnetic recording layer because
the layer is thick or has a high Young's modulus.

FIG. 2 is a schematic sectional view showing the
arrangement of the second example of the magnetic
15   recording medium of the present invention. A magnetic
recording medium 20 shown in FIG. 2 has the same
structure as shown in FIG. 1 except that a multi-layer
6 is formed instead of the multi-layer 4. In the
multi-layer 6, a magnetic recording layer 2 is formed
20   on a high-magnetostriction layer 3 via an interlayer
such as an underlayer 5.

For example in one embodiment, the high-
magnetostriction layer may have a saturation magnetic
field larger than the coercive force of the magnetic
25   recording layer, and moreover in another embodiment the
high-magnetostriction layer has a saturation magnetic
field larger than that of the magnetic recording layer.

If the saturation magnetic field of the high-magnetostriction layer is smaller than the coercive force of the magnetic recording layer, the deformations of the high-magnetostriction layer caused by the magnetostriction stops at the same time the magnetic field saturates even when the head magnetic field is made larger than the saturation magnetic field of the high-magnetostriction layer. Consequently, no large inverse magnetostriction effect can be obtained, and this tends to result in an insufficient increase in recording resolution and medium S/N ratio.

The high-magnetostriction layer can be a single high-magnetostriction film having high magnetostriction or a multi-layer of the high-magnetostriction film and another film having other characteristics.

For example, when the saturation magnetic field of the high-magnetostriction layer is smaller than the coercive force of the magnetic recording layer, the saturation magnetic field of the high-magnetostriction layer can be made larger than the coercive force of the magnetic recording layer by using a multi-layer including a high-magnetostriction film and a film whose anisotropic magnetic field is larger than the coercive forces of the high-magnetostriction film and magnetic recording layer. In this structure, even when a head magnetic field larger than the coercive force of the magnetic recording layer is applied, the deformation

of the high-magnetostriction layer caused by the
magnetostriction does not stop, so a large inverse
magnetostriction effect can be obtained.

The same effect can also be obtained by using a
multi-layer including a high-magnetostriction film and
a film having large forced magnetostriction which
appears when spins are forcedly oriented by an external
magnetic field larger than the saturation magnetic
field.

The above example uses characteristics which
decrease the magnetic anisotropy by magnetostriction
when a magnetic field is applied. However, this
example can also be used to increase the thermal decay
resistance by increasing the magnetic anisotropy of the
recording layer by magnetostriction when a magnetic
field is applied.

FIG. 3 is a schematic sectional view showing the
third example of the magnetic recording medium of the
present invention.

As shown in FIG. 3, a magnetic recording medium 30
has the same structure as shown in FIG. 1 except that a
multi-layer 12 is formed instead of the multi-layer 4.
The multi-layer 12 includes a double-layered high-
magnetostriction layer 11 having a film 7 whose
anisotropic magnetic field is larger than that of a
high-magnetostriction film and a high-magnetostriction
film 8 formed in this order on a substrate 1, and a

magnetic recording layer 3 formed on the high-magnetostriction film 11.

It is also possible to form a film having large forced magnetostriction in place of the film 7 whose anisotropic magnetic field is larger than that of the high-magnetostriction film.

The high-magnetostriction film has a large magnetostriction constant of preferably 5×10^{-5} or more, more preferably 5×10^{-5} to 4×10^{-4}, and most preferably 1×10^{-4} to 4×10^{-4}, in the magnetic field application direction. When this magnetostriction constant is 5×10^{-5}, a sufficient strain can be given to the magnetic recording layer, so it is possible to further reduce the anisotropic dispersion and effectively improve the medium characteristics.

The magnetic recording layer has a Young's modulus of preferably 10^{12} to 10^{10} (N/m^2), and more preferably 10^{11} (N/m^2). In practice, a high-magnetostriction material can be selected in accordance with the magnetic characteristics of the magnetic recording layer.

When a magnetic recording layer having the Young's modulus and magnetostriction constant as described above is used, strain is readily produced by the influence of the high-magnetostriction layer, so the magnetic anisotropy decreases more effectively by the inverse magnetostriction effect. The change in

magnetic anisotropy by the inverse magnetostriction
effect is not large when compared with the magnitude
of the crystallomagnetic anisotropy of a Co alloy.
However, this change is not negligibly small when
compared with the magnitude of magnetic anisotropy
dispersion, and can have a favorable effect on the
coercive force dispersion.

Also, the change in magnetic anisotropy by the
inverse magnetostriction effect cannot be ignored when
compared with the value of Hn representing the reverse
magnetic domain generating magnetic field of the
recording layer. Accordingly, the thermal decay
resistance can also be increased.

For instance, in some embodiments, as the magnetic
recording layer, a perpendicular magnetic recording
layer can be used.

This perpendicular magnetic recording layer can
have either a single-layered structure or multilayered
structure. When a multilayered structure is used, the
manufacturing process is complicated, but various
characteristics required of the perpendicular magnetic
recording layer can be controlled relatively easily.
Examples of the characteristics required of the
perpendicular magnetic recording layer are that
the perpendicular direction is the easy axis of
magnetization, the layer has magnetic anisotropy and
alignment with which data can be well written by the

recording head magnetic field, recording bits are stable at both high density and low density although the magnetization unit is fine and noise is low, and no magnetization reversal occurs due to an unnecessary

5   external magnetic field or adjacent recording.

For example, as the perpendicular magnetic recording layer, in one embodiment, a hexagonal closest packed (hcp) Co alloy can be used. When a Co alloy having this hcp structure is stretched in the direction

10 of the easy axis of magnetization, the c/a axis ratio of crystal increases, so the magnetic anisotropy can be decreased. Therefore, as a high-magnetostriction film used in the perpendicular magnetic recording medium, it is possible to use a film having positive

15 magnetostriction in the magnetic field direction and negative magnetostriction in a direction perpendicular to the magnetic field. Accordingly, when a perpendicular magnetic field appears, this high-magnetostriction film expands in a direction

20 perpendicular to the surface of the substrate, and contracts in the direction of the surface of the substrate. Especially when a hexagonal closest packed (hcp) magnetic film such as Co alloy film is used as the magnetic recording layer, if the direction of the

25 easy axis of magnetization and the magnetic field application direction are the same, no magnetostriction is generated by this Co alloy-based magnetic film

alone, so the high-magnetostriction material can function more effectively.

Even when a longitudinal magnetic recording layer is used, the head magnetic field is applied in the horizontal direction because a ring head is used. Therefore, a high-magnetostriction material having a positive magnetostriction constant in a direction parallel to the film surface can be combined with a longitudinally oriented Co alloy film.

As this high-magnetostriction film material, it is possible to use, e.g., RFe_2-based materials such as $Sm_{0.5}Dy_{0.5}Fe_2$, $Tb_xDy_{1-x}Fe_2$, $TbFe_2$ (oriented in [111]), and $ErFe_2$, Fe_3Pt, an Fe/Pt stacked film, an Fe/Pd stacked film, an FeAl alloy, a rare earth element-containing Co alloy, and a ferrite-based material. The magnetostriction of any of these magnetostriction materials can be increased by orientation. Also, when nitrogen or oxygen is added to these magnetostriction materials, noise from the high-magnetostriction layer can be reduced.

Examples of a cobalt alloy usable as the magnetic recording layer material are CoCrPt, CoCrPtB, CoCrPtC, CoCrPtTa, CoCrPtCu, CoCrPtRu, CoCrPtCuB, CoCrPtRuB, CoCrPtTaNd, CoCrPtWC, CoCrPtO, CoPtO, $CoPt-SiO_2$, $CoCrPt-SiO_2$, $CoPtO-SiO_2$, and $CoPtCrO-SiO_2$. It is also possible to use, e.g., a Co/Pd stacked layer, Co/Pt stacked layer, and FePt.

For example, it is possible to use a Co alloy as a
main element, add Pt to increase the anisotropy, weaken
the magnetic interaction between grains to make the
magnetic unit fine, and add Cr, oxygen, or SiO_2 to make

5   high-density recording feasible. When the magnetic
recording layer is formed, Cr readily segregates in the
crystal grain boundary by substrate heating or the
like. Accordingly, the magnetic recording layer can
take a favorable structure in which the Co alloy

10   crystal in which the C axis of hpc is aligned
perpendicularly to the substrate is magnetically
separated and made fine by Cr. Even when oxygen or
SiO_2 is added, a Co oxide, Cr oxide, or SiO_2 segregates
in the grain boundary to make this grain boundary

15   portion nonmagnetic, so oxygen or SiO_2 also functions
in the same manner as Cr. When oxygen is used, the
grain size can be further decreased without any
substrate heating.

        An underlayer can be formed to form the magnetic

20   recording layer.

        As this underlayer by which the crystal anisotropy
of the crystal grains of the magnetic recording layer
can be oriented in the perpendicular direction, it is
possible to preferably use a material, such as a

25   nonmagnetic CoCr-based material or Ru-based material,
which takes the hcp structure or fcc structure, in
which the closest packed face readily grows parallel to

the substrate, and which has a lattice constant close to that of the recording layer.

Also, a seed layer can be formed before the underlayer is formed. Examples of the seed layer for the underlayer capable of orienting the crystal anisotropy in the perpendicular direction are Ti, Pt, Pd, Au, NiAl, Hf, Ru, Ge, NiTa, CoNiTa, NiNb, CoNiNb, Ag, Al, Si, and C.

At a position separated from a recording track, the head magnetic field is applied in a direction different from the track position. Therefore, the high-magnetostriction layer so acts as to increase the anisotropy of the magnetic recording layer. In this manner, the head magnetic field effectively functions against the problem that information on an adjacent track is erased during recording.

Examples of the underlayer capable of orienting the crystal anisotropy of the crystal grains in the magnetic recording layer in the longitudinal direction are Cr, CrV, CrNb, CrMo, CrW, CrB, CrCu, V, VCr, Nb, NbCr, and NbV. As the seed layer, it is possible to use NiAl, FeAl, TiN, MgO, Ag, Al, and C.

When a perpendicular magnetic recording layer is to be formed as the magnetic recording layer, a soft magnetic layer can be formed between this perpendicular magnetic recording layer and the substrate.

When a soft magnetic layer having high magnetic

permeability is formed, a so-called double-layered perpendicular medium having a perpendicular magnetic recording layer on this soft magnetic layer is obtained. In this double-layered perpendicular medium, the soft magnetic layer performs part of the function of a magnetic head, i.e., horizontally passes the recording magnetic field from a magnetic head, e.g., a single pole head for magnetizing the perpendicular magnetic recording layer, and returns the recording magnetic field to the magnetic head. That is, the soft magnetic field applies a steep sufficient perpendicular magnetic field to the magnetic recording layer, thereby increasing the recording/reproduction efficiency.

As the soft magnetic material, it is possible to use CoZrNb, FeCoB, FeCoN, FeTaC, FeTaN, FeNi, and FeAlSi, each of which has a high saturation magnetic flux density and favorable soft magnetic charac-teristics.

In addition, a bias application layer such as a longitudinal hard magnetic film or antiferromagnetic film can be formed between the soft magnetic layer and substrate. The soft magnetic layer readily forms a magnetic domain, and this magnetic domain generates spike noise. The generation of a magnetic wall can be prevented by applying a magnetic field in one direction of the radial direction of the bias application layer, thereby applying a bias magnetic field to the soft

magnetic layer formed on the bias application layer. It is also possible to give the bias application layer a stacked structure to finely disperse the anisotropy and make a large magnetic domain difficult to form.

Examples of the bias application layer material are CoCrPt, CoCrPtB, CoCrPtTa, CoCrPtC, CoCrPtCuB, CoCrRuB, CoCrPtWC, CoCrPtWB, CoCrPtTaNd, CoSm, CoPt, CoPtO, CoCrPtO, CoPt-SiO$_2$, and CoCrPtO-SiO$_2$.

FIG. 4 is a schematic sectional view showing the arrangement of the fourth example of the magnetic recording medium of the present invention.

As shown in FIG. 4, a magnetic recording medium 40 has the same structure as shown in FIG. 1 except that between a substrate 1 and a multi-layer 4 having a magnetic recording layer 2 and high-magnetostriction layer 3, a bias application layer 13 and soft magnetic layer 14 are formed in this order from the substrate 1.

In addition, a low-elasticity layer having a Young's modulus lower than that of the soft magnetic layer can also be formed between the soft magnetic layer and multi-layer.

This low-elasticity layer is selected in accordance with the material of the soft magnetic layer. For example, it is possible to use a low-melting material such as tin, lead, indium, or bismuth, or a polymer material such as polyester or polyimide.

FIG. 5 is a schematic sectional view showing the arrangement of the fifth example of the magnetic recording medium of the present invention.

As shown in FIG. 5, a magnetic recording medium 50 has the same structure as shown in FIG. 4 except that a low-elasticity layer 15 is formed between a multi-layer 4 and soft magnetic layer 14.

Referring to FIG. 4, a nonmagnetic underlayer (not shown) for improving the perpendicular orientation of the magnetic recording layer can also be formed on the soft magnetic layer 14. This underlayer also has a function of causing magnetic separation between the recording layer and soft magnetic layer, thereby preventing degradation of the characteristics of the soft magnetic layer. As the underlayer, for example, in some embodiments, it is possible to use a material, such as a nonmagnetic CoCr-based material or Ru-based material, which takes the hcp structure or fcc structure, in which the closest packed face readily grows longitudinal to the substrate, and which has a lattice constant close to that of the recording layer. This underlayer can be a single layer or two or more multi-layers in order to control the grain size or improve the orientation even when the thickness is small.

FIG. 6 is a partially exploded perspective view showing an example of the magnetic

recording/reproducing apparatus of the present invention.

A rigid magnetic disk 121 for recording information according to the present invention is fitted on a spindle 122 and rotated at a predetermined rotational speed by a spindle motor (not shown). A slider 123 mounting a single pole recording head for accessing the magnetic disk 121 to record information and an MR head for reproducing information is attached to the end portion of a suspension 124 which is a thin leaf spring. The suspension 124 is connected to one end of an arm 125 having, e.g., a bobbin which holds a driving coil (not shown).

A voice coil motor 126 as a kind of a linear motor is attached to the other end of the arm 125. This voice coil motor 126 includes the driving coil (not shown) wound around the bobbin of the arm 125, and a magnetic circuit having a permanent magnetic and counter yoke opposing each other on the two sides of the driving coil.

The arm 125 is held by ball bearings (not shown) formed in two, upper and lower portions of a fixed shaft 127, and pivoted by the voice coil motor 126. That is, the position of the slider 123 on the magnetic disk 121 is controlled by the voice coil motor 126. Reference numeral 128 in FIG. 6 denotes a lid.

Embodiments

Embodiment 1

A 2.5-inch, hard-disk-like crystallized glass substrate was placed in a sputtering apparatus, and the apparatus was evacuated to 1×10^{-5} Pa or less. After that, the substrate was heated at 1,700 W for 7 sec, and sputtering was performed at an Ar pressure of 0.6 Pa by using an Ni-50at%Al target, thereby forming a 5-nm thick NiAl film as a seed layer.

Subsequently, a 5-nm thick Cr alloy underlayer for orienting a hard magnetic film in the longitudinal direction was formed on the NiAl film. On this Cr alloy underlayer, a 15-nm thick Co-19at%Cr-14at%Pt-1at%Cu-1at%B hard magnetic film for applying a bias magnetic field to a soft magnetic film was formed.

In addition, on the thus obtained hard magnetic film, a 2-nm thick Co-26at%Cr-15at%Ru weak magnetic film was formed to control the magnetization fixing strength between the longitudinal hard magnetic film and a soft magnetic film on it. On this weak magnetic film, a 100-nm thick Co-5at%-Zr-8at%Nb film and 20-nm thick Co-6at%Ta-2at%Zr film were formed as a soft magnetic layer.

Furthermore, on this soft magnetic layer, a 5-nm thick Ni-40at%Ta film and a 15-nm thick Co-26at%Cr-12at%Pt-4at%B film having a high Cr

composition to function as an initial growth layer of a magnetic recording layer were formed as orientation control layers.

After that, a multi-layer was formed on this film by first forming a 20-nm thick Co-19at%Cr-16at%Pt-1at%B film having a magnetostriction constant of 1×10^{-5} as a perpendicular magnetic recording layer, and then forming a 4-nm thick $Sm_{0.5}Dy_{0.5}Fe_2$ high-magnetostriction film having a magnetostriction constant of 2×10^{-4} larger than that of the magnetic recording layer.

After a 6-nm thick carbon film was formed on this multi-layer by CVD, a perfluoropolyether (PFPE) film having a thickness of 1 nm or more was formed as a lubricating layer by dip coating, thereby obtaining a perpendicular magnetic recording medium A-1.

A pulse magnetic field of 1,185 kA/m (15 kOe) or more was applied to the obtained perpendicular magnetic recording medium A-1 in the radial direction by using a magnetizing apparatus, in order to orient magnetization of the longitudinal hard magnetic film in the radial direction, thereby applying a bias magnetic field to the soft magnetic layer. In this manner, magnetic domains were removed from the soft magnetic film.

FIG. 7 shows the arrangement of the obtained medium A-1.

As shown in FIG. 7, the medium A-1 has an

arrangement in which a seed layer 16, an underlayer 17, a hard magnetic layer 18, a weak magnetic layer 19, a soft magnetic layer 20 made up of soft magnetic films 20a and 20b, a first orientation control layer 21, a

5   second orientation control layer 22, a multi-layer 25 made up of a perpendicular magnetic recording layer 23 and high-magnetostriction film 24, a carbon layer 26, and a lubricating layer (not shown) are stacked in this order on a substrate 1.

10   Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed on the obtained medium A-1. The obtained results are shown in Table 1 (to be presented later).

15   The magnetic characteristics of the medium A-1 evaluated by using the Kerr effect were that the perpendicular coercive force (perpendicular Hc) was 280.45 kA/m (3,550 Oe), a squareness ratio Rs was 0.92, and a reverse magnetic domain generating magnetic field

20   Hn was 63.2 kA/m (800 Oe). As is apparent from the relationship between the perpendicular coercive force and Hn, the slope of the MH loop of the obtained perpendicular magnetic recording medium was steep, indicating high recording resolution.

25   The recording/reproduction characteristics of the medium A-1 were evaluated by using a head including a 0.25-μm wide single pole recording head and 0.22-μm

wide GMR reproducing element and corresponding to a floating amount of 15 nm. As an index of the recording resolution, a half-width PW50 of the waveform obtained by differentiating a solitary reproduction wave was 8.2 nanoseconds, a favorable value. Also, a ratio (medium noise ratio) SNm of noise (rms value) to a low-frequency solitary signal at a recording density of 500 kFCI of a reproduction wave processed by a differentiating circuit was 23.3 dB.

Control 1

For comparison, a perpendicular magnetic recording medium B-1 was manufactured following the same procedures as for the medium A-1 of Embodiment 1 except that no $Sm_{0.5}Dy_{0.5}Fe_2$ film was formed.

Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed on the obtained medium B-1 in the same manner as in Embodiment 1. The obtained results are shown in Table 1 (to be presented later).

The characteristics of the medium B-1 were that the perpendicular coercive force was 300.2 kA/m (3,800 Oe), the squareness ratio Rs was 0.90, the reverse magnetic domain generating magnetic field Hn was 23.7 kA/m (300 Oe), the value of PW50 was 9.1 nanoseconds, and the value of SNm was 22.6 dB.

The medium A-1 was superior in recording

resolution and SNm to the medium B-1. Also, since the

value of Hn of the medium A-1 increased, an output

reduction by thermal decay was -0.15%/decade in

the medium B-1 but improved to -0.12%/decade in the

5   medium A-1.

Embodiment 2

Following the same procedures as in Embodiment 1,

a 5-nm thick Ni-50at%Al seed film and 5-nm thick

Cr-20at%Mo alloy film were formed on a crystallized

10   glass substrate. In addition, a multi-layer was

formed as a longitudinal magnetic recording layer

on this alloy film by first forming a 20-nm thick

Co-20at%Cr-16at%Pt-8at%B film, and then forming a 4-nm

thick $ErFe_2$ high-magnetostriction film having large

15   magnetostriction.

After that, a carbon film and lubricating layer

were formed following the same procedures as in

Embodiment 1, thereby obtaining a longitudinal magnetic

recording medium A-2.

20   FIG. 8 is a schematic sectional view showing the

arrangement of the obtained longitudinal magnetic

recording medium A-2.

As shown in FIG. 8, this longitudinal magnetic

recording medium has an arrangement in which a seed

25   layer 16, an underlayer 17, a multi-layer 29 made up

of a longitudinal magnetic recording layer 27 and

high-magnetostriction layer 28, a carbon protective

layer 26, and a lubricating layer (not shown) are stacked in this order on a substrate 1.

Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed on the obtained longitudinal magnetic recording medium A-2. The obtained results are shown in Table 2 (to be presented later).

Control 2

For comparison, a longitudinal magnetic recording medium B-2 was obtained following the same procedures as for the medium A-2 except that no $ErFe_2$ high-magnetostriction film was formed.

Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed on the obtained longitudinal magnetic recording medium B-2. The obtained results are shown in Table 2 (to be presented later).

The characteristics of the medium A-2 of Embodiment 2 were that the longitudinal coercive force (longitudinal Hc) was 355.5 kA/m (4,500 Oe), a longitudinal squareness ratio S was 0.86, and a coercive force squareness ratio S^* was 0.82. As is apparent from the value of S^*, the slope of the MH loop was steep, indicating high recording resolution.

In addition, the recording/reproduction

characteristics were evaluated by using a head
including a 0.25-μm wide single pole recording head and
0.22-μm wide GMR reproducing element and corresponding
to a floating amount of 15 nm. As an index of the
5 recording resolution, the half-width PW50 of a solitary
waveform was 9.0 nanoseconds, a favorable value. Also,
the value of SNm at a recording density of 500 kFCI was
23.1 dB.

The characteristics of the medium B-2 were that
10 the longitudinal coercive force was 379.2 kA/m
(4,800 Oe), the longitudinal squareness ratio was 0.78,
the value of PW50 was 9.2 nanoseconds, and the SNm
ratio was 22.6 dB.

As described above, the medium A-2 was superior in
15 recording resolution and SNm to the medium B-2.

Embodiment 3

Following the same procedures as in Embodiment 1,
a seed layer, underlayer, hard magnetic layer, weak
magnetic layer, and soft magnetic layer made up of two
20 soft magnetic films were formed on a substrate. In
addition, on the soft magnetic layer, a 5-nm thick tin
layer (E = 5 $\times$ 10^{10} N/m^2) was formed such that the
Young's modulus was smaller than that of a CoZrNb film
(E = 1 $\times$ 10^{11} N/m^2) so as not to transmit strain to
25 the underlying soft magnetic film. Furthermore, on
this tin layer, a 4-nm thick $Sm_{0.5}Dy_{0.5}Fe_2$ high-
magnetostriction film (2 $\times$ 10^{-4}) was formed. On this

film, a 5-nm thick Ni-40at%Ta film and 15-nm thick

Co-26at%Cr-12at%Pt-4at%B film similar to those of

Embodiment 1 were formed as orientation control layers.

On these orientation control layers, a 20-nm thick

5   Co-19at%Cr-16at%Pt-1at%B film having a magnetostriction

constant of 10^{-5} order was formed as a perpendicular

recording layer.

Since the tin film having high hardness and a

small Young's modulus was formed between the film

10   having a large magnetostriction constant and the soft

magnetic film, the influence of magnetostriction was

not easily transmitted to the soft magnetic film, so it

was possible to reduce changes in characteristics of

the soft magnetic film. A carbon film and lubricating

15   layer were formed on the resultant structure following

the same procedures as in Embodiment 1, thereby

obtaining a perpendicular magnetic recording medium

A-3.

After that, a pulse magnetic field was applied to

20   the medium A-3 in the radial direction by using a

magnetizing apparatus in the same manner as in

Embodiment 1, thereby orienting magnetization of the

longitudinal hard magnetic film in the radial

direction.

25   FIG. 9 is a schematic sectional view showing the

arrangement of the medium A-3.

As shown in FIG. 9, the perpendicular magnetic

recording medium A-3 has an arrangement in which a seed layer 16, an underlayer 17, a hard magnetic layer 18, a weak magnetic layer 19, a soft magnetic layer 20 made up of soft magnetic films 20a and 20b, a low-elasticity

5 layer 31, a multi-layer 32, and a carbon layer 26 are stacked in this order on a substrate 1. The multi-layer 32 has a high-magnetostriction film 24, first orientation control layer 21, second orientation control layer 22, and perpendicular magnetic recording

10 layer 23 formed in this order on the low-elasticity layer 31.

Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed

15 on the obtained medium A-3 in the same manner as in Embodiment 1. The obtained results are shown in Table 1 (to be presented later).

The magnetic characteristics of the medium A-3 were that the perpendicular coercive force was

20 284.4 kA/m (3,600 Oe), the squareness ratio Rs was 0.91, and the reverse magnetic domain generating magnetic field Hn was 31.6 kA/m (400 Oe). As is apparent from the relationship between the perpen- dicular Hc and Hn, the slope of the MH loop of the

25 medium A-3 was steep, indicating high recording resolution, compared to the medium B-1 in which neither a high-magnetostriction film nor a low-elasticity film

was formed.

When the recording/reproduction characteristics were evaluated following the same procedures as in Embodiment 1, the half-width PW50 was 8.3 nanoseconds, a favorable value. Also, the value of SNm was 23.1 dB. The medium A-3 was superior in recording resolution and SNm to the medium B-1. In addition, since the value of Hn of the medium A-3 increased, an output reduction by thermal decay was -0.15%/decade in the medium B-1 but improved to -0.13%/decade in the medium A-3.

Embodiment 4

A perpendicular magnetic recording medium A-4 was obtained following the same procedures as in Embodiment 1 except that on a perpendicular magnetic recording layer, a 2-nm thick $PtFe_3$ film having a large magnetostriction constant of 1×10^{-4} and a 2-nm thick $Co_{80}Pt_{20}$ film having anisotropy Hk larger than a saturation magnetic field Hs of the magnetic recording layer were formed in this order in place of the $Sm_{0.5}Dy_{0.5}Fe_2$ high-magnetostriction film.

A pulse magnetic field was applied to the obtained medium A-4 in the radial direction in the same manner as in Embodiment 1, thereby aligning magnetization of the longitudinal hard magnetic film in the radial direction.

Also, a medium A-5 was manufactured following the same procedures as for the medium A-4 except that no

$Co_{80}Pt_{20}$ film was formed.

After that, a pulse magnetic field was applied to the medium A-5 in the radial direction by using a magnetizing apparatus in the same manner as in Embodiment 1, thereby orienting magnetization of the longitudinal hard magnetic film in the radial direction.

FIG. 10 is a schematic sectional view showing the arrangement of the medium A-4.

As shown in FIG. 10, the medium A-4 has the same arrangement as the medium A-1 shown in FIG. 7 except that a perpendicular magnetic recording layer 23, high-magnetostriction film 33, and high-Hk film 34 are formed on a second orientation control layer 22, instead of the multi-layer 25 made up of the perpendicular magnetic recording layer 23 and high-magnetostriction film 24.

FIG. 11 is a schematic sectional view showing the arrangement of the medium A-5.

As shown in FIG. 11, the medium A-5 has the same arrangement as the medium A-1 shown in FIG. 7 except that a perpendicular magnetic recording layer 23 and high-magnetostriction film 33 are formed on a second orientation control layer 22, instead of the multi-layer 25 made up of the perpendicular magnetic recording layer 23 and high-magnetostriction film 24.

Kerr effect measurement and electromagnetic

conversion characteristic evaluation (recording/
reproduction characteristic evaluation) were performed
on the obtained media A-4 and A-5 in the same manner as
in Embodiment 1.   The obtained results are shown in

5   Table 1 (to be presented later).

The magnetic characteristics of the medium A-4
were that the perpendicular coercive force was
284.4 kA/m (3,600 Oe), the squareness ratio Rs was
0.93, and the reverse magnetic domain generating

10   magnetic field Hn was 43.45 kA/m (550 Oe).

When the recording/reproduction characteristics
were evaluated following the same procedures as in
Embodiment 1, the half-width PW50 was 8.2 nanoseconds,
a favorable value. Also, the value of SNm was 23.4 dB.

15   The characteristics of the medium A-5 were that
the perpendicular coercive force was 252.8 kA/m
(3,200 Oe), the squareness ratio Rs was 0.90, the
reverse magnetic domain generating magnetic field Hn
was 27.65 kA/m (350 Oe), the value of SNm was 23.0 dB,

20   and the value of PW50 was 8.7 nanoseconds, which was
larger than that of medium A-4 but better than that of
the medium B-1.

As described above, the media of the present
invention were superior in the recording resolution and

25   SNm. In addition, since the value of Hn of the medium
A-4 increased, an output reduction by thermal decay
was -0.15%/decade in the medium B-1 but improved

to -0.11%/decade in the medium A-4. Likewise, the
output reduction of the medium A-5 was -0.13%/decade,
better than that of the medium B-1.

Embodiment 5

5   A perpendicular magnetic recording medium A-6
was obtained following the same procedures as in
Embodiment 1 except that instead of the multi-layer
made up of the perpendicular magnetic recording
layer and high-magnetostriction film, a multi-layer

10   was formed by forming a 12-nm thick
Co-19at%Cr-16at%Pt-1at%B film having an easy axis of
magnetization in the perpendicular direction as a
perpendicular magnetic recording layer, a 2-nm thick
$Sm_{0.5}Dy_{0.5}Fe_2$ high-magnetostriction film having a

15   magnetostriction constant of 2×10^{-4} as an interlayer,
and an 8-nm thick Co-19at%Cr-16at%Pt-1at%B film in this
order.

After that, a pulse magnetic field was applied to
the medium A-6 in the radial direction by using a

20   magnetizing apparatus in the same manner as in
Embodiment 1, thereby orienting magnetization of the
longitudinal hard magnetic film in the radial
direction.

FIG. 12 is a schematic sectional view showing the

25   arrangement of the medium A-6.

As shown in FIG. 12, the medium A-6 has the same
arrangement as the medium A-1 except that a multi-layer

38 made up of a perpendicular magnetic recording layer 23, high-magnetostriction film 37, and perpendicular magnetic recording layer 23 is formed on a second orientation control layer 22, instead of the multi-
5   layer 25.

Kerr effect measurement and electromagnetic conversion characteristic evaluation (recording/ reproduction characteristic evaluation) were performed on the obtained medium A-6 in the same manner as in
10   Embodiment 1. The obtained results are shown in Table 1 (to be presented later).

The magnetic characteristics of the medium A-6 were that the perpendicular coercive force was 272.55 kA/m (3,450 Oe), the squareness ratio Rs was
15   0.91, and the reverse magnetic domain generating magnetic field Hn was 31.6 kA/m (400 Oe). As is apparent from the relationship between the perpen- dicular Hc and Hn, the slope of the MH loop of the medium A-6 was steep, indicating high recording
20   resolution.

When the recording/reproduction characteristics of this medium were evaluated following the same procedures as in Embodiment 1, the half-width PW50 was 8.3 nanoseconds, a favorable value. Also, the value of
25   SNm was 23.5 dB.

As described above, the medium A-6 was superior in the recording resolution and SNm to the medium B-1. In

addition, since the value of Hn of the medium A-6 increased, an output reduction by thermal decay improved to -0.12%/decade compared to the medium B-1.

Embodiment 6

A perpendicular magnetic recording medium A-7 was obtained following the same procedures as in Embodiment 1 except that a 5-nm thick Ti film and 5-nm thick Ru film were formed instead of the Ni-40at%Ta orientation control layer and Co-26at%Cr-12at%Pt-4at%B underlayer, a 20-nm thick CoPtCrO film was formed as a perpendicular magnetic recording layer on the Ti and Ru films by performing sputtering in an Ar ambient containing oxygen by using a Co-20at%Pt-16at%Cr target, and a 4-nm thick $Tb_{0.5}Dy_{0.5}Fe_2$ high-magnetostriction film having a magnetostriction constant of 4×10^{-4} was formed as a high-magnetostriction film on the perpendicular magnetic recording layer.

After that, a pulse magnetic field was applied to the medium A-7 in the radial direction by using a magnetizing apparatus in the same manner as in Embodiment 1, thereby orienting magnetization of the longitudinal hard magnetic film in the radial direction.

FIG. 13 is a schematic sectional view showing the arrangement of the medium A-7.

As shown in FIG. 13, the medium A-7 has the same arrangement as Embodiment 1 except that orientation

control layers 39 and 41 are formed instead of the

first and second orientation control layers 21 and 22,

and a multi-layer 44 made up of a perpendicular

magnetic recording layer 42 containing oxygen and

5   high-magnetostriction film 43 is formed instead of the

multi-layer 25.

For comparison, a conventional perpendicular

magnetic recording medium B-3 was formed following the

same procedures as for the medium A-7 except that no

10   $Tb_{0.5}Dy_{0.5}Fe_2$ high-magnetostriction film was formed.

Kerr effect measurement and electromagnetic

conversion characteristic evaluation (recording/

reproduction characteristic evaluation) were performed

on the obtained media A-7 and B-3.

15   The obtained results are shown in Table 3 (to be

presented later).

The magnetic characteristics of the medium A-7

were that the perpendicular coercive force was

331.8 kA/m (4,200 Oe), the squareness ratio Rs was

20   0.94, and the reverse magnetic domain generating

magnetic field Hn was 67.15 kA/m (850 Oe). As is

apparent from the relationship between Hc and Hn,

the slope of the MH loop of the medium was steep,

indicating high recording resolution.

25   When the recording/reproduction characteristics

were evaluated following the same procedures as in

Embodiment 1, the half-width PW50 was 7.8 nanoseconds,

a favorable value.   Also, the value of SNm at a
recording density of 500 kFCI was 23.3 dB.

On the other hand, the characteristics of the
conventional medium B-3 were that the perpendicular Hc
was 355.5 kA/m (4,500 Oe), the squareness ratio Rs was
0.94, the reverse magnetic domain generating magnetic
field Hn was 47.4 kA/m (600 Oe), the value of PW50 was
8.3 nanoseconds, and the value of SNm was 22.4 dB.

As described above, the medium A-7 was superior in
the recording resolution and SNm to the medium B-3.   In
addition, since the value of Hn of the medium A-7 was
larger than that of the medium B-3, an output reduction
by thermal decay improved to -0.10%/decade while that
of the medium B-3 was -0.12%/decade.

Table 1

Medium	Hc (kA/m)	Rs	Hn (kA/m)	PW50 (nsec)	SNm (dB)	Output reduction (%/decade)
A-1	280.45	0.92	63.2	8.2	23.2	-0.12
A-3	284.4	0.91	47.4	8.3	23.1	-0.13
A-4	284.4	0.93	71.1	8.2	23.4	-0.11
A-5	252.8	0.90	27.65	8.7	23.0	-0.13
A-6	272.55	0.91	39.5	8.3	23.5	-0.12
B-1	276.5	0.90	23.7	9.1	22.6	-0.15

Table 2

Medium	Hc (kA/m)	S	S*	PW50 (nsec)	SNm (dB)
A-2	355.5	0.86	0.82	8.6	23.1
B-2	379.2	0.84	0.78	9.2	22.6

Table 3

Medium	Hc (kA/m)	Rs	Hn (kA/m)	PW50 (nsec)	SNm (dB)	Output reduction (%/decade)
A-7	331.8	0.94	67.15	7.8	23.2	-0.10
B-3	355.5	0.94	47.4	8.3	22.4	-0.12

In the present invention as described above, the coercive force dispersion of a magnetic recording medium is substantially decreased. This makes it possible to increase the recording resolution by decreasing the magnetization transition width, increase the medium S/N ratio by decreasing the magnetization transition length of the magnetic recording medium and making its anisotropic magnetic field Hk uniform, ensure a high thermal decay resistance, and record and reproduce high-density information.

Additional advantages and modifications will readily occur to those skilled in the art. Therefore, the invention in its broader aspects is not limited to the specific details and representative embodiments shown and described herein. Accordingly, various modifications may be made without departing from the spirit and scope of the general inventive concept as defined by the appended claims and their equivalents.